

Program

Keynote

- K01** »AI between Hype and Industrial-Grade«
Rolf Hellinger, Siemens, DE
- K02** »Infrastructure Requirements for Electrified Heavy Goods Transport in Germany and the EU«
Martin Wietschel, Daniel Speth, Steffen Link, Fraunhofer Institute ISI, DE
- K03** »Challenges and Solutions to Power Latest Processor Generations for Hyper Scale Datacenters«
Gerald Deboy, Matthias Kasper, Martin Wattenberg, Roberto Rizzolatti, Infineon Technologies, AT

GaN Ruggedness

- OP001** **An Improved Ultrafast Desaturation-Based Protection Scheme for GaN HEMT**
Juncheng Lu, Hossein Khoun Jahan, Hamidreza Esmaeilian, Lei Kou, Roy Hou, Infineon Technologists, CA;
Xiaoyu Wang, Carleton University, CA
- OP002** **The Performance of a GaN eMode HEMT in Surge Current Scenarios such as the Active Short Circuit**
Dominik Nehmer, Mark-M. Bakran, University of Bayreuth, DE
Maximilian Hepp, Wolfgang Wondrak, Mercedes-Benz, DE
- OP003** **Gate Resistance Effect on Short-Circuit Robustness of p-GaN HEMTs**
Mohamed Lemine Dedew, Valeria Rustichelli, Joao Oliveira, Maroun Alam, Fabio Coccetti, IRT Saint Exupery, FR
Stéphane Lefebvre, Tien Anh Nguyen, Matthieu Landel, SATIE, FR
Le Thanh Long, Safran, FR

Advanced Packaging Technologies

- OP004** **Neural Network Assisted Numerical Simulation Benchmarking for Electric Vehicle Thermal Management System**
Ekin Alp Bicer, Pascal Schirmer, Peter Schreivogel BMW, DE
Gabriele Schrag, Technical University of Munich, DE
- OP005** **Relationship Between Porosity in Cu Sintered Bonding and Bonding Reliability**
Hideo Nakako, Michiko Natori, Dai Ishikawa, Kazuhiko Minami, Seiji Matsushima, Resonac, JP
- OP006** **High Thermal Durability of Thin Copper Die-attach Layers and Finite Element Model Simulation**
Takaaki Eyama, Shuichi Inaya, Ukyo Suzuki, Taiki Fukuda, Takumi Miyamoto, Masafumi Takesue, Kao, JP

Thermal Cycling Reliability

- OP007** **Thermal Shock Test Lifetime Improvement with Optimized Adhesive Strength between Epoxy Resin and Copper**
He Kangjia, Seiichi Hayakawa, Yukihiro Kumagai, Kan Yasui, Takayuki Kushima, Mineba Power Semiconductor Device, JP
Kisho Ashida, Osamu Ikeda, Hitachi, JP
- OP008** **Power Cycling Reliability and Failure Mode Analysis of POL**
Kenichi Koi, Jumpei Tokutake, Koji Bando, Shinko Electric Industries, JP

- OP009 Accelerated Power Cycling of GaN HEMTs using Switching Loss and Fast Temperature Measurement**
Wing Tai Leung, Mehdi Niroomand, Saeed Jahdi, Bernard Stark, University of Bristol, UK

High Power Converters

- OP010 Control of an MMC-Based Hybrid Transformer with Star-Point Voltage Injection**
Rui Wang, Henk Huisman, C.G.E. (Korneel) Wijnards, Eindhoven University of Technology, NL
- OP011 Protection and Control of a Dual MMC Medium Voltage Supply**
Max Dupont, Drazen Dujic, EPFL, CH
- OP012 Station Power Electronics Converter with High Thermal Endurance to Pole-To-Pole Short Circuits for LVDC Distribution Grid**
Frédéric Reymond-Laruina, Djamel Hadbi, Philippe Egrot, EDF R&D, FR
Loïc Quéval, Damien Huchet, Marc Petit, GeePs, FR
Stéphane Mercier, Socomec, FR
Gustavo Alves de Lima Henn, IEDS-UNILAB, BR

Gate Drivers

- OP013 Suppression of Oscillations in a SiC Bridge-Leg using a Custom Single-Chip Digital Active Gate Driver with 2×255 Strength Levels**
Qilei Wang, Harry Dymond, University of Bristol, UK
Dawei Liu, Guangdong Academy of Sciences, CN
Yushi Wang, Saeed Jahdi, Bernard Stark, University of Bristol, UK
- OP014 SiC MOSFET Short-Circuit Protection: A Faster Soft Shut Down Method for Gate Drivers**
Julien Weckbrodt, Le Thanh Long, Safran, FR
Nicolas Ginot, Christophe Batard, Louison Gouy, University of Nantes, FR
- OP015 Parameter Identification: Gate Sensor for Power Transistor Tolerance Compensation in Advanced Gate Driver Ics**
Christopher Wille, Andreas Menzel, Thoralf Rosahl, Rakshith Satheesh, Pushkar Kulkarni, Robert Bosch, DE

Advanced Control Techniques on Electrical Drives I

- OP016 An Innovative High-Speed Track Range Restart Strategy for Permanent Magnet Synchronous Motor**
Anna Corbitt, Weiping Fu, Hao Chen, Cheng Tang, Yuyang Wang, H. Alan Mantooth, University of Arkansas, US
- OP017 Steady-State Error Reduction of Reinforcement Learning Based Indirect Current Control of Permanent Magnet Synchronous Machines**
Tobias Schindler, Lara Broghammer, Nina Diring, Benedikt Hofmann, Dennis Hufnagel, Armin Dietz, Nuremberg Institute of Technology, DE
Ralph Kennel, Technical University of Munich, DE
Petros Karamanakos, Tampere University, FI
- OP018 Performance Comparison of Using Shunt-based and Integrated Current Sensing for Sensorless Field-Oriented Control**
John Emmanuel Tan, Juan Paolo Quismundo, Jhaebhee Mark Calderon, Power Integrations, PH

GaN Converters

- OP019 Design of High-Power Inverter with 12 Parallel GaN Devices**

Takashi Sawada, Hiroshi Tadano, Koji Shiozaki, Nagoya University, JP
Shunsuke Takuma, Yoshiya Ohnura, Nagaoka Power Electronics, JP

OP020 Over 99.7% Efficient GaN-Based 6-Level Capacitive-Load Power Converter
Stefan Mönch, Richard Reiner, Patrick Waltereit, Rüdiger Quay, Michael Basler, Fraunhofer
Institute IAF, DE
Kilian Bartholomé, Fraunhofer Institute IPM, DE

OP021 Cascaded Primary-Side-Only Control of a Compact 2 MHz 500 W Wireless Power Transfer System
Tim Krigar, Martin Pfof, Tim Egener, TU Dortmund University, DE

Advanced Materials and Technologies

OP022 Power Module Evaluation Using Ultra High Heat Dissipation and High Heat Resistance Resin Sheet Containing Card House Type Boron Nitride Filler
Ayano Imai, Katsuhiko Hidaka, Shuji Suzuki, Jun Matsui, Toshiyuki Sawamura, Yuya Koga,
Mitsubishi Chemical, JP
Yasushi Yamada, Daido University, JP
Shinichi Yasaka, Kanagawa Institute of Industrial Science and Technology, JP
Hitoshi Habuka, Yokohama Jisso Consotium, JP

OP023 Investigating Temperature Dependent Warpage in Metal Ceramic Substrates for Power Electronics Devices
Benjamin Fabian, Daniel Schnee, Sebastian Fritzsche, Peter Prenosil, Marco Müller,
Heraeus Electronics, DE
Felix Koser, University of Applied Sciences Aschaffenburg, DE

OP024 Degradation Mode Analysis of Different Bonding Technologies of SiC Power Semiconductors Stressed by Active Power Cycling
Rasched Sankari, Ulrich Kessler, Martin Rittner, Thomas Kaden, Manfred Reinold, Robert
Bosch, DE
Martin Schneider-Ramelow, Fraunhofer Institute IZM, D

Charging Station Technology

OP025 Implementation and Verification of a 50kW Opportunity Wireless Charger Design
Carlos Costas Sos, Juan Manuel Pere Buil, Irene Maria Torres Alfonso, Antonio Miguel
Munoz Gomez, CIRCE Foundation, ES

OP026 Performance Evaluation of Silicon-Based 3-Level Vienna Rectifier in ISOPLUS SMPD Package
Karsten Haehre, Muhammad Yassof, Littelfuse, DE

OP027 Performance Analysis of a 25-kW SiC-Based Dual Active Bridge Converter Based on Parallel-Connected Devices
Francesco Porpora, Mauro Di Monaco, Giuseppe Tomasso, Vito Nardi, University of Cassino
and Southern Lazio, IT
Daniele Marciano, Emanuele Di Fazio, E-Lectra, IT
Maurizio Granato, Analog Devices, IT
Eric Benedict, Ryan Schnell, Analog Devices, US

Modelling and Monitoring

OP028 Semiconductor Chip Models are the Key for Enabling Virtual Design and Optimization Workflows of Power Electronic Systems
Stefan Haensel, Sebastian Nielebock, Christian Raduege, Rolf Hellinger, Markus Pfeifer,
Siemens, DE
Abby Shih, Keysight Technologies, DE

- OP029 Improved Resonant Frequency-Based Parasitic Inductance Estimation Method for SiC MOSFET Half-Bridge Circuit**
Hongpeng Zhang, Felix Steiner, Horst Demattio, Thomas Blank, Karlsruhe Institute of Technology, DE
- OP030 Fast Simulator with Inverter Temperature Estimation for Traction eDrives in Vehicles Subjected to Driving Cycles**
Simone Giuffrida, Iustin Radu Bojoi, Luisa Tolosano, Fabio Mandrile, Polytechnical University of Turin, IT
Claudio Romano, Maurizio Tranchero, Ideas&Motion, IT

Solid State Transformers

- OP031 A New Family of Three-Phase-Unfolder-Based MVAC-LVDC Solid-State Transformers**
Jonas Huber, Johann Kolar, ETH Zurich, CH
Uwe Drofenik, Francisco Canales, ABB, CH
- OP032 Voltage Balancing of a Split-Capacitor IGCT 3L-NPC Leg for the Resonant DC Transformer**
Renan Pillon Barcelos, Drazen Dujic, EPFL, CH
- OP033 Comparative Analysis of Unidirectional High Step-Up Converters for Medium Voltage Applications**
Stefan Subotic, Drazen Dujic EPFL, CH
Ralph Burkart, Thomas Gradinger, Hitachi Energy, CH

Advanced Control Techniques on Electrical Drives II

- OP034 Startup Behavior of Harmonic Suppression in Electrical Machines Using Iterative Learning Control and Neural Networks**
Annette Mai, Maximilian Hofmann, Fraunhofer Institute IISB, DE
Bernhard Wagner, Nuremberg Institute of Technology, DE
- OP035 Analytical Approach of the Vector Current Control Flux-Weakening Strategy for Permanent Magnet Synchronous Machines**
Oriol Subirats Rillo, Daniel Montesinos i Miracle, Samuel Galceran Arellano, Carlos Miguel Espinar, UPC, ES
- OP123 Statistical Variations in the Parasitic Capacitance of a Coil**
Kevin Talits, Claas Tebrügge, HELLA, DE
Martin Pfof, TU Dortmund University, DE

Power Electronics for E-Mobility

- OP036 Investigation on Direct Liquid Cooling Design of Power Modules with Flat Baseplate for Automotive Application**
Nobuhide Arai, Shinichiro Adachi, Kensuke Matsuzawa, Takahiro Koyama, Takanori Shintani, Fuji Electric, JP
Steffen Ewald, Fuji Electric, DE
- OP037 A Novel Approach for Affordable Electric Vehicles Based on Dual 48V Battery System with Multi-functional 3-Level Converter**
Radovan Vuletic, Dušan Graovac, Infineon Technologies, DE
Tatsuya Arai, Infineon Technologies, JP; Akihiro Furukawa, Mazda Motor, JP
- OP038 An Innovative 3-level Solution for Automotive Applications: eMPack**
Pranav Panchal, Arendt Wintrich, Oliver Tamm, Ole Muehlfeld, Semikron-Danfoss, DE
- OP039 Gated Recurrent Units-Assisted State-Space Modeling for Electric Vehicle Temperature Prediction**
Xinyuan Liao, Shaowei Chen, Northwestern Polytechnical University, CN;

Shuai Zhao, Aalborg University, DK

- OP040 Novel Bidirectional Single-Stage Isolated 600-V GaN M-BDSBased Single/Three-Phase-Operable EV On-Board Charger**
Sven Weihe, Johann Kolar, David Menzi, Jerome Kaufmann, Jonas Huber, Daifei Zhang, ETH Zurich, CH
Matthias Kasper, Kenneth Kin Leong, Gerald Deboy, Infineon Technologies, AT

Encapsulation Materials

- OP041 Application-Specific Investigation of Inorganic Potting Material in Drive Trains**
Soenke Fleck, Ulf Schuemann, University of Applied Sciences Kiel, DE
- OP042 The Influence of the Glass Transition Temperature of Epoxy Mold Compounds on the Reliability of a Semiconductor Device**
Stefan Schwab, Christoph Liebl, Alexander Roth, Infineon Technologies, DE
Timo Mueller, Infineon Technologies, SGP



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Best Paper Award

- OP043 Corrosion Resistant Packaging for Power Semiconductor Modules - Modified Insulation Materials for Contaminated Environments**
Michael Hanf, Nando Kaminski, University of Bremen, DE
Andreas Brinkmann, Andrea Deißberger, Volkmar Stenzel, Fraunhofer Institute IFAM, DE
- OP044 Investigation of Inorganic Encapsulation Materials in Power Electronic Systems for High Power Density Applications**
Stefan Behrendt, Semikron Danfoss, DE
Christophe Fery, Tamara Albert, Heraeus Electronics, DE
Christiane Plikat, Volkswagen, DE
Rüdiger Knofe, Siemens, DE
Soenke Fleck, Ulf Schuemann, University of Applied Sciences Kiel, DE
- OP045 Characterization of Thermally Aged Silicone Gels for Power Semiconductor Modules**
Sonja Madloch, Thomas Spann, Littelfuse, DE
Elaheh Arjmand, Littelfuse, Meghna De, UK
Philip Fletcher, University of Bath, UK

Power Quality

- OP046 A Coordinated Control of Hybrid Single-Phase AC/DC Microgrids Based on the Natural Harmonic Injection Concept**
Mehdi Baharizadeh, Mohammad Sadegh Golsorkhi Esfahani, Thomas Ebel, University of Southern Denmark, DK
- OP047 A High-Power Density SiC Based TP PFC with High-Frequency Ripple Cancellation Leg**
Serkan Dusmez, Huawei Technologies DE
Ali Tausif, Ahmet Faruk Bakan, Yildiz Technical University, TR
- OP048 High Frequency Active Filter for AC-DC High Power Converters**
Sarah Sifoune, Denis Labrousse, Pierre-Etienne Lévy, Cyrille Gautier, Bertrand Revol, Safran, F
- OP049 Laboratory Setup for Accuracy Investigation of Electricity Meters and Monitors under Industry-Typical Operating Conditions**
Matthias Schmidt, Xiaofei Guo, Robin Abraham, Physikalisch-Technische Bundesanstalt (PTB), DE
Michael Freiburg, Felix Hackeloeer, Lukas Christ, Technical University Cologne, DE
Christian Brennecke, ZERA, DE

Grid Connected Converters

- OP050 Real-Time Evaluation of Weighting Factorless Predictive Control of LCL Filter Equipped Grid-Side Converters using Sorting Networks**
Kristóf Bándy, Péter Stumpf, Zoltán Sütő, Budapest University of Technology and Economics, HU
- OP051 Relaxed Robust Control with Pragmatic Shortage of Passivity for Wind, Storage and PV Power Converters**
Sergio de Lopez Diz, Pablo Moreno, Andres Agudo, Ana Rodríguez, Luis Diez, Mario Rizo, Gamesa Electric, ES
- OP052 An Effective DC Voltage Regulation of Active Front-End Rectifier through Model Predictive Control**
Mobina Pouresmaeil, Edris Pouresmaeil, Jorma Kyrrä, Aalto University, FI
- OP053 Bi-directional 11kW Multi-Level Active-Neutral-Point-Clamped AC-DC Converter Using 600V/750V Si Super-Junction and SiC MOSFETs for High-Efficiency and High-Density Applications**
Mengxing Chen, Manuel Escudero Rodriguez, Matteo-Alessandro Kutschak, Alex Rossi, Infineon Technologies, AT
David Meneses Herrera, Infineon Technologies, FI
- OP054 A Study of Grid-Forming Inverter Control Strategy for Fault-Ride-Through Capability**
Hirofumi Uemura, Sachio Takano, Fuji Electric, JP

Passive Components

- OP055 Film Capacitors for High Temperature AC-DC Inverter Applications**
Adel Bastawros, Fumio Yu, Sabic, JP
Takashi Mori, Kenichi Oshita, Nichicon, JP
- OP056 Loss Reduction in HF-Transformers using Laminated Ferrite E-Cores**
Lukas Reißenweber, Julia Rogner, Alexander Stadler, Coburg University of Applied Sciences and Arts, DE
- OP057 Multigap Toroidal Transformer and Inductors for Overcoming Fringing Losses in High Frequency Converters**
Pau Colomer, Marc Maneja, David Prados, Prax, ES
- OP058 Study on Sample Geometries for Ferrite Characterisation in the MHz Range**
Till Piepenbrock, Joachim Böcker, Sebastian Schachten, Frank Schafmeister, Paderborn University, DE
Lukas Keuck, HELLA, DE
- OP059 FEM-Supported and Non-Destructive Magnetic Characterization Method for Non-Laminated Steel**
Stefan Tobler, Simon Nigsch, Eastern Switzerland University, CH

Drives for High Demanding Applications



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Young Researcher Award

OP060 Highly-Compact Bearingless Axial-Flux Motor for a Pediatric Implantable Fontan Blood Pump

Andreas Horat, Rosario Vincenzo Giuffrida, Jonas Huber, Johann Kolar, ETH Zurich, CH
Spasoje Miric, University of Innsbruck, AT
Marcus Granegger, Medical University of Vienna, AT

OP061 A Novel Permanent Magnet Synchronous Motor Drive for Reaction Wheels in Satellites

Baris Colak, Suleyman Cetinkaya, TUBITAK UZAY Space Technologies Research Institute, TR

OP062 Exploring High Frequency Operation of Motor Drives: Practical Insights on Efficiency and Loss

Asantha Kempitiya, Hrach Amirkhanian, Steve Oknaian, Infineon Technologies, US
Jannik Gade, Infineon Technologies, AT

OP063 High Power Density System Design for GaN-based LV Motor Drives

Marco Cannone, Edward Jones, Martin Wattenberg, Infineon Technologies, AT

OP064 Design of GaN Transistor based Variable Speed Drive Inverter with Output Voltage Filtering

Kaspars Kroics, Valerijs Maricevs, Riga Technical University, LV
Ugis Sirmelis, Energotronix, LV

IGBT

OP065 The 8TH Generation LV100 IGBT Module with Higher Current Rating

Daichi Otori, Masaomi Miyazawa, Mitsubishi Electric, JP
Koichi Masuda, Eugen Stumpf, Mitsubishi Electric, DE

OP066 New Planar 4.5 kV Split-gate (SG) Si-IGBT Device for Improved Switching Characteristics and High Frequency Operation

Gaurav Gupta, Jeremy Jones, Boni Boksteen, Babak Nikberg, Luca De Michielis, Hitachi Energy, CH; Gontran Pâques, Hitachi Energy Research, CH

OP067 4.5 kV Double-Gate Reverse-Conducting Press-Pack IEGT

Satoshi Yoshida, Tatsunori Sakano, Atsushi Yamaoka, Tomoaki Inokuchi, Kazuto Takao, Toshiba, JP
Ryohei Gejo, Takahiro Kato, Toshiba Electronic Devices & Storage, JP

Device Concepts

OP068 Evaluation of a 3 kV Polarization Superjunction GaN HEMT

Alireza Sheikhan, Sankara Narayanan Ekkanath Madathil, University of Sheffield, UK
Hiroji Kawai, Shuichi Yagi, Hironobu Narui, Powdec, JP

OP069 More than 1200 V Breakdown and Low Area-Specific On State Resistances by Progress in Lateral GaN-on-Si and GaN-on-Insulator Technologies

Richard Reiner, Stefan Müller, Patrick Waltereit, Fouad Benkhelifa, Stefan Mönch, Michael Basler, Michael Mikulla, Rüdiger Quay, Fraunhofer Institute IAF, DE

- OP070 Novel 200 V MOSFET Technology Pushes Motor Drive Inverter Efficiency to an Unprecedented Level**
Mark Thomas, Ralf Siemieniec, Elvir Kahrimanovic, Laszlo Juhasz, Michael Hutzler, Infineon Technologies, AT
Kapil Kelkar, Infineon Technologies, US

Degradation Mechanisms

- OP071 Moisture Robust Chip Design - Improved Edge-Terminations for High Lifetime under High Humid Conditions**
Michael Hanf, Nando Kaminski, University of Bremen, DE
Arnost Kopta, Power Device Technology, CH
Yanrui Ju, Raffael Schnell, SwissSEM Technologies, CH
- OP072 Method for Measuring the Initial State of a Solder Joint Delamination in a 3D PCB Integration Assembly of SiC MOSFETs**
Souhila Bouzard, Laurent Dupont, University Gustave Eiffel, FR
Mickael Petit, SATIE, FR
Vincent Bley, Céline Combettes, University of Toulouse, FR
- OP073 Generic Lifetime Model for Wire Bonds Degradation in IGBT Modules Based on a Fracture Mechanics Parameter**
Merouane Ouhab, Nicolas Degrenne, Mitsubishi Electric, FR
Yusaku Ito, Masaki Taya, Mitsubishi Electric, JP

Advanced Conversion Concepts

- OP074 Modular Coaxial Power Converter for High-Density Integration into Medium-Voltage Cables**
Mark Cairnie, Aakash Kamalapur, Jack Knoll, Qingrui Yuchi, Rajaie Nassar, Christina DiMarino, Khai Ngo, Guo-Quan Lu, Qiang Li, Jung-Soo Bae, Dushan Boroyevich, Virginia Polytechnic and State University, US
Jierui Zhou, Yang Cao, University of Connecticut, US
Doug DeVoto, Bidzina Kekelia, National Renewable Energy Lab, US
- OP075 Controlled Inductor Based BCM Buck Converters**
Ziv Gellman, Sam Ben-Yaakov, Iris Eting, Yivgeni Semidotskih, Ben Gurion University, IL
- OP076 Influence of Varying Common Mode Choke Sizes on the Performance and Stability of an Active EMI Filter**
Patrick Körner, Philip Brockerhoff, Felix Müller, Vitesco Technologies, DE
Marco Jung, Bonn-Rhein-Sieg University of Applied Sciences, DE

Photovoltaic Systems

- OP077 A High Efficiency Battery Charger with Maximum Power Point Tracking for Magnetic Energy Harvesters**
Antonio Miguel Munoz Gomez, Javier Ballestin Fuertes, CIRCE Foundation, ES
Jose Francisco Sanz Osorio, Zaragoza University, ES
- OP078 Symmetric Flying-capacitor Boost Converter for Medium-voltage Photovoltaic Applications**
Luis Alves Rodrigues, Guillaume Piquet-Boisson, Arnaud Revel, Anthony Bier, Stéphane Catellani, CEA, FR
- OP079 Comparison of Si IGBT, SiC MOSFET and Adjustable Hybrid Switch PV Inverters for Different Geographical Locations**
Tanya Thekemuriyil, Dario Schneider, Jaspera Dominique Rohner, Silvia Mastellone, Renato Amaral Minamisawa, University of Applied Sciences and Arts Northwestern Switzerland, CH
Munaf T.A. Rahimo, MTAL, CH
Vipluv Aga, Solextron, CH

Model Based System Analysis

- OP080 Optimising a Power Module for Electrical and Thermal Performance and Symmetry Using EDA Tools**
Wilfried Wessel, Andreas Schwarzbacher, Technical University of Dublin, IE
Florian Bauer, Siemens EDA, DE
Christian Jakob, University of Applied Sciences Darmstadt, DE
Roland Bártai, Gergő Juhasz, Vincotech, HU
- OP081 Conductor-Based Modeling of Voltage Distribution along a Single-Tooth Winding of Electrical Machines**
Hujun Peng, Yue Yu, Svetomir Stevic, Niklas Driendl, Kay Hameyer, RWTH Aachen University, DE
- OP082 Reduction of PWM Harmonics with Carrier Phase Shifting in a Dual-Stator PMSM with Magnetic Coupled Windings**
Bünyamin Tekir, Robert Zipprich, Jan Winter, Marcus Ziegler, University of Kassel, DE

SiC Devices

- OP083 The New CoolSiC MOSFET 1200 V G2: Electrical Performance and Compact Modelling**
Andreas Huerner, Qing Sun, Rudolf Elpelt, Infineon Technologies, DE
- OP084 Paralleling SiC-Power-MOSFET Body Diodes under Harsh Switching Conditions**
Michael Rauh, Mark-M. Bakran, University of Bayreuth, DE
Matthias Bürger, Infineon Technologies, DE
- OP085 3.3kV SBD-Embedded SiC-MOSFET Module for Traction Use**
Yoichi Hironaka, Shigeru Okimoto, Mamoru Matsuo, Shota Saito, Kenji Hatori, Mitsubishi Electric, JP
Nils Soltau, Mitsubishi Electric, DE
- OP086 Dead Time Optimization for High Power SiC MOSFET Module in Consideration of Parasitic Components**
Pham Ha Trieu To, Hao Wang, Florian Sawallich, Felix Kayser, Hans-Günter Eckel, University of Rostock, DE

WBG Reliability

- OP087 Performance Instability of 650 V p-GaN Gate HEMT Device under Temperature-related Positive Gate Bias Stresses**
Renze Yu, Saeed Jahdi, Phil Mellor, University of Bristol, UK
Jose Ortiz Gonzalez, Olayiwola Alatise, University of Warwick, UK
- OP088 Gate Oxide Reliability of Current Generation 1.2 kV SiC MOSFETs under Step-Wise Increased Gate Voltage**
Roman Boldyrjew-Mast, Sven Thiele, Thomas Basler, Chemnitz University of Technology, DE
- OP089 An Accelerated Dynamic Gate Switching Stress Test Concept of SiC MOSFETs at High Drain-Source Voltage (HV-GSS)**
Clemens Herrmann, Sven Thiele, Dezhi Yang, Thomas Basler, Chemnitz University of Technology, DE
Matthias Neumeister, Markus Pfeifer, Siemens, DE
- OP090 Silicon Carbide Power Device Use in Spacecraft and Aircraft**
Akin Akturk, Ethan Mountfort, Christopher Darmody, Mitchell Gross, Bryce Galey, Usama Khalid, Neil Goldsman, CoolCAD Electronics, US

Power Electronics for E-Mobility/ Control

OP091 Current Ripple Reduction by Combination of Si IGBT and SiC MOSFETs in Heavy Duty Fuel Cell Trucks
Yavuz Gürlek, Firat Yüce, Martin Ackerl, Roland Dold, Daimler Truck, DE
Thomas Basler, Chemnitz University of Technology, DE
Martin Neuburger, Esslingen University, DE

OP092 Evaluation of Active Gate Drivers with Switchable Gate Resistors and Intermediate Voltage Levels for SiC MOSFETs in WLTC
Michael Frank, Mark-M. Bakran, University of Bayreuth, DE

OP093 Performance Evaluation of TCM-based, Zero-Voltage Switching (ZVS) Three-Phase Inverter for Electric Vehicle Drive Systems
Khizra Abbas, Hans-Peter Nee, KTH Royal Institute of Technology, SW



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Best Paper Award

OP094 A Partial Load Three-Phase Triangular Current Mode Modulation Concept with an Optimized Filter Inductor for High Efficiency Traction Drives
Bhaskar Chatterjee, Jan Allgeier, Thomas Plum, Robert Bosch, DE
Marc Hiller, Karlsruhe Institute of Technology, DE

DC-DC Converters I

OP095 GaN vs Si Synchronous Rectifier for LLC Converter
Gokhan Sen, Milko Paolucci, Sriram Jagannath, Infineon Technologies, AT
Ahmet Cem Gungor, RWTH University Aachen, DE
Serkan Dusmez, Huawei Technologies, DE

OP096 Co-Simulation Design of a GaN-Based Three-Phase LLC Converter with Integrated Three-Phase Magnetics
Jhih-Cheng Hu, Ming-Shi Huang, Shih-Cyuan, Kuo, Hong-Xuan Liao, National Taipei University of Technology, TW

OP097 Switching Assisting Circuit Improving the Efficiency of DC-DC Converters Based on Piezoelectric Resonators
Ghislain Despesse, Valentin Breton, Emile Bigot, CEA Leti, FR
François Costa, SATIE, FR

OP098 Transformer-based Fixed-ratio Resonant DC-DC Converters for 48V Data Centers
Xufu Ren, Teng Long, Jinfeng Zhang, University of Cambridge, UK
Jibin Song, Lei Wang, Pengcheng Xu, EPIC Tech, CN

PFC Converters

OP099 High-Density 3.3 kW GaN Rectifier for Server Applications Comprising a 130 kHz Totem-Pole PFC and a 500 kHz LLC
Manuel Escudero Rodriguez, Matteo-Alessandro Kutschak, Antonello Laneve, Infineon Technologies, AT
David Meneses Herrera, Infineon Technologies, FI

OP100 Addressing Power Switch Technology Selection Si/SiC/GaN in High Efficiency ZVS-PFC Resonant Converters
Marco Torrisi, Sebastiano Messina, Angelo Giordano, Daniele Giovanni Sfilio, STMicroelectronics, IT
Mario Cacciato, University of Catania, IT

OP101 Buck-Type Current Unfolding Converter with Discontinuous Conduction Mode in Ultra-Low Power-Factor Operation

Tomoyuki Mannen, Boseung Seo, Takanori Isobe, University of Tsukuba, JP
Ha Pham, University of Technology Sydney, AU

OP102 GaN Based Bi-Directional 6.6kW Interleaved Totem-Pole PFC with 13kW/L Power Density and High Efficiency

Juncheng Lu, Esmail Jalalabadi, Infineon Technologies, CA
Yang Jiao, Infineon Technologies, US; Xiaoyu Wang, Carleton University, CA

SiC Modules

OP103 The Design of a 2kV 1700A SiC MOSFET Dual Module

Jorge Mari, Tobias Schuetz, Xiaoting Dong, Yanfeng Shen, Michael Kirner, Luigi Findanno, Semikron Danfoss, DE

OP104 Technological approaches to high-power density SiC power module for automotive

Takeshi Tokorozuki, Hideo Komo, Rei Yoneyama, Gourab Majumdar, Mitsubishi Electric, JP
Kazuhiro Nishimura, Melco Semiconductor Engineering, JP

OP105 Extremely Compact SiC Power Module for EV Traction Inverters in the 250 kW Class

Raffael Schnell, Guillemin Rémi, Roger Stark, Sven Matthias, SwissSEM Technologies, CH
Samuel Hartmann, MFIS, CH
Li Coris, Sunking Pacific Semiconductors Technology, CN

OP106 Benefits of .XT Interconnection Technology for 3.3 kV XHP 2 Module with 3.3 kV CoolSiC MOSFET

Matthias Bürger, Tobias N. Wassermann, Infineon Technologies, DE

Advanced Cooling

OP107 Large-Area Bonding with LMEE: Suppression of the Degradation of the Junction-to-Water Thermal Resistance in Power Modules

Yo Mochizuki, ROHM Semiconductor, JP
Takukazu Otsuka, Ken Nakahara, ROHM, JP
Navid Kazem, Dylan Shah, Arieca, US

OP108 Active Thermal Control of SiC MOSFETs Utilizing Transient Thermal Characterization

Varaha Satya Bharath Kurukuru, Md. Nazmul Hasan, Roberto Petrella, Silicon Austria Labs, AT

OP109 Thermal Management Solutions by Additive Manufacturing – Powder Bed Fusion and Diffusion Bonding

Simon Jahn, Felix Gemse, Steffen Dahms, ifw Jena - Günter-Köhler-Institute, DE

OP110 Advanced Pumped Two-Phase Cold Plate for Cooling Power Electronics

Elizabeth Seber, Michael Ellis, Advanced Cooling Technologies, US

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OP111 Feasibility Study of High-Power Density Isolated CLLC DC-DC Interface with Wide Range of Voltage/Current Regulation

Oleksandr Husev, Dmitri Vinnikov, Oleksandr Matiushkin, Parham Mohseni, Tallinn University of Technology, EE
Francisco Canales, ABB, CH

OP112 DC-Bias Reduction in High-Frequency Dual Active Bridge DC-DC Converters through Slow DC Measurements

Patrick Lenzen, Martin Pfost, TU Dortmund University, DE

- OP113 Optimized Current Sharing Technique for Interleaved CLLC Converters for Minimal Output Current Distortion**
Martin Gendrin, Akshay Mahajan, Fraunhofer Institute ISE, DE
- OP114 Primary-side Output Regulation Principles in Dynamic Multi-MHz Inductive Power Transfer Systems and Isolated DC/DC Converters**
Ioannis Nikiforidis, Paul Mitcheson, Prateek Wagle, Imperial College London, UK
Roberto La Rosa, STMicroelectronics, IT

Smart Grid

- OP115 Low Voltage DC-Grids with Galvanic Isolation: System Discussion, Efficiency and Performance Comparison to AC-Feeding**
Lukas Fräger, Sascha Langfermann, Michael Owzareck, BLOCK Transformatoren-Elektronik, DE
Andreas Schnieder, Herbert Kannegiesser, DE
Dennis Kampen, City University of Applied Sciences Bremen, DE
Jens Friebe, University of Kassel, DE
- OP116 Implementation and Experimental Evaluation of an Adaptive DC Grid Controller for Decentralised Grid Control**
Steffen Menzel, René Reimann, Lorenz Grundhoff, Wilfried Holzke, Bernd Orlik, University of Bremen, DE
- OP117 Demonstrating the Effectiveness of a DC Solid-State Circuit Breaker's Fast Response Time**
Ehab Tarmoom, Steven Chenetz, Dennis Meyer, Jason Chiang, Microchip Technology, US
- OP118 Modelling and Sizing Sensitivity Analysis of a Fully Renewable Energy-based Electric Vehicle Charging Station Microgrid**
David A. Stone, Mobin Naderi, Diane Palmer, Maria N. Munoz, Matthew Smith, Erica E.F. Ballantyne, Daniel T. Gladwin, Martin P. Foster, University of Sheffield, UK
Yazan Al-Wreikat, Ewan Fraser, University of Southampton, UK

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- OP119 LED Powered Rotor Telemetry System**
Raphael Beyerle, Manfred Schrödl, Technical University of Vienna, AT
- OP120 'Infinity Gate Sensor': a Differential Magnetic Field Sensor for Measuring Gate Current of SiC Power Transistors**
Yushi Wang, Qilei Wang, Matthew Appleby, Jiaqi Yan, Harry Dymond, Saeed Jahdi, Bernard Stark, University of Bristol, UK
- OP121 Characterising Wide Bandgap Power Modules: Validating the M-Shunt Concept for High-Power Applications in the Kiloampere Range**
Hauke Lutzen, Jonas Müller, Lennart Dittmer, Nando Kaminski, Malte Arndt, University of Bremen, DE
Till Huesgen, Vladimir Polezhaev, Kempten University of Applied Sciences, DE
Steffen Chemnitz, SubCtech, DE



- OP122 Characterization of Power-Module Parasitics: Sub-Nanosecond Large Signal Pulsing vs. Double-Pulse Testing**
Gerhard Groos, Dennis Helmut, Felix Gesele, Thomas Brückner, Universität der Bundeswehr München, DE

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- PP001 A 4.5 kV Fast Recovery Diode Platform for High-Current IGBTs**
Jan Vobecky, Martin Stencel, Josef Hylsky, Ladislav Radvan, Hitachi Energy, CZ
Umamaheswara Reddy Vemulapati, Urban Meier, Chiara Corvasce, Hitachi Energy, CH
- PP002 6.5 kV Innovative Silicon Power Device (i-Si) Module with High Power Density and Low Loss by Stored Carrier Control**
Takashi Hirao, Tomoyuki Miyoshi, Hiroshi Suzuki, Yusuke Takada, Tomoyasu Furukawa, Yusuke Kanno, Yasuhiko Kono, Katsumi Ishikawa, Mutsuhiro Mori, Hitachi, JP
Tsubasa Moritsuka, Masaki Shiraishi, Isamu Yoshida, Takayuki Kushima, Hitachi Power Semiconductor Device, JP
- PP003 High Current Density 4.5kV PressPack IGBTs Push SOA Limits**
Hossein Davoodi, Peter Waind, Paolo Mirone, Littelfuse, DE
Liutauras Storasta, Littelfuse, CH
Geo Joseph, Paul Hailes, Julian Pitman, Littelfuse, UK
- PP004 2.5kV IGBT Module with High Reliability for Renewable Applications**
Akiyoshi Masuda, Masaomi Miyazawa, Tsuyoshi Uraji, Mitsubishi Electric, JP
Koichi Masuda, Narender Lakshmanan, Thomas Radke, Mitsubishi Electric, DE
- PP005 New Generation 4.5kV IGCT and Fast Recovery Diode for Railway Power Supply Applications**
Umamaheswara Reddy Vemulapati, Remo Baumann, Tobias Wikström, Thomas Stiasny, Chiara Corvasce, Christian Winter, Hitachi Energy, CH
- PP006 Next Generation 4.5 kV IGBT-Only StakPak Module with Reduced Losses and High Temperature Capability**
Jeremy Jones, Gaurav Gupta, Boni Boksteen, Evgeny Tsyplakov, Makan Chen, Luca De Michielis, Gontran Pâques, Hitachi Energy, CH

Thermal Modelling and Simulations

- PP007 Finite Element Analysis of the upscaling of Warpage and Bifurcation Hysteresis Loops: from Cu/Si Die to Large Wafers**
Vincenzo Vinciguerra, Giuseppe Luigi Malgioglio, Marco Renna, STMicroelectronics, IT
- PP009 Maximum Junction Temperature Simulation and Validation for the Hot Spot in Multi-Chip SiC Power Module**
Wonjin Dylan Cho, Byoungok Lee, Hansol Seo, Udaykumar Vangaveti, onsemi, US
- PP010 Integration of CFD-Simulation Results in PLECS Using Lookup Tables**
Simon Cebin, Holger Borchering, University of Applied Sciences and Arts Ostwestfalen-Lippe, DE
- PP011 PCB Only Thermal Management Techniques for eGAN FETs in a Half-Bridge Configuration**
Adolfo Herrera, Alejandro Pozo Arribas, Michael de Rooij, Efficient Power Conversion, US

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- PP013 From 4x to 3x STPAK – Optimization for a More Compact EV Traction Inverter Solution**
Vittorio Giuffrida, Simone Buonomo, Massimiliano Chiantello, STMicroelectronics, IT
- PP014 A Multi-objective Structural Optimization Method Based on Multi-Physics Simulations for Power Module**
Baihan Liu, Mengyao Du, Yiyang Yan, Jianwei Lv Huazhong, Cai Chen, Yong Kang, Huazhong University of Science and Technology, CN

- PP015 Holistic Approach to Maximize Lifetime and Power Density in High Power Semiconductor Modules**
Martin Schulz, Lukas Kreiner, Ralf Klemmer, Littelfuse, DE
- PP016 Regulated High Density Switch Capacitor Topology**
Pierrick Ausseresse, Infineon Technologies, DE
- PP017 Silicon Interposer as a Substrate for Power Modules with High Power Density and Superior Thermal Performance**
Ahmed Ammar, Ömer Altan, Shuangyue Yang, Sebastian Tengvall, Junghyun Kang, Yasser Nour, Hoa Le Thanh Lotus Microsystems, DK

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- PP018 Analytical Modeling and Stability Characterization of a Damped VSCC CM Active EMI Filter for Single- and Three-Phase AC-DC Applications**
Timothy Hegarty, Ben Chan, Robert Blattner, Texas Instruments, US
Ashish Kumar, Our Next Energy, US
- PP019 An Active Bridge Circuit with High Ability to Withstand Surge for Outdoor Lighting Application**
Liang Shi, Kang Li, Tom Tang, Zephyr Zhao, Signify, CN
- PP020 A Repetitive High Voltage Nanosecond Pulse Generator: First Prototype Design and Test Results**
Serge Gavin, Simon Kissling, Mauro Carpita, University of Applied Sciences of Western Switzerland, CH
Bertrand Daout, Frédéric Castella, Montena Technology, CH
- PP021 Frequency Shift Keyed Dual Side Control of Inductive Power Transfer: An Application of Talkative Power Conversion**
Hamzeh Beiranvand, Julius Maximilian Placzek, Marco Liserre, University of Kiel, DE
- PP022 Study of a Multi-Active Bridge Converter for a Domestic Electrical Grid**
Abdenmour Merrouche, Thierry Talbert, University of Perpignan, FR
Daniel Matt, Thierry Martiré, Guillaume Pellecuer, University of Montpellier, FR

Integration Technologies and Reliability Design

- PP023 Fabrication Development for Gate Driver Embedded Double-Sided Cooling SiC Power Module for Electric Vehicle Application**
Anna Corbitt, Hao Chen, Cheng Tang, Weiping Fu, H. Alan Mantooth, University of Arkansas, US
Yuyang Wang, Riya Paul, Wolfspeed, US
- PP024 Printed Circuit Embedding of Prepackaged 150V Power MOSFETs in a Portable Welding Application**
Thomas Gebhard, Infineon Technologies, AT
Franz Musil, FRONIUS INTERNATIONAL, AT
Manuel Schumann, Unimicron, DE
- PP025 Process Challenges and Progress Towards Direct Connection of Automotive Power Modules (TMM) to Heatsink**
Indrajit Paul, Inpil Yoo, STMicroelectronics, DE
Sergio Savino, Gaetano Montalto, Ettore Chiacchio, Alessandro Tumminia, Francesco Salamone, STMicroelectronics, IT
- PP026 Optimizing PCB Stackups for Enhanced GaN Transistor Performance in High-Power Applications**
Philipp Czerwenka, Jan Frederik Wagenfeld, Gernot Schullerus, Reutlingen University, DE

- PP027 New Generation Ceramic Substrates – Key Components for Power Electronic Applications: Processing and Characterization**
Stefanie Schindler, Tanja Einhellinger-Müller, Linda Schicker, Hans-Ulrich Völler, CeramTec, DE
- PP028 AI-Enhanced Vacuum Reflow Oven: Precision Control for Reliable Large-Area Soldering**
Chih Hui Lee, Liu Ta-Chung, Mustec, TW
Shiue Yow-Ling, Pan Cheng-Tang National Sun Yat-Sen University, TW
I Lin Tsung, Lighten, TW
Yen Chung-Kun, I-Shou University, TW
Wang Shao-Yu, NPERC-J, TW
- PP030 Corrosion-Compatible Drive Electronics for Electric Vehicles and Industrial Power Modules**
Tom Petzold, Ronald Eisele, Armin Hindel, Bennet Lorbeer, Markus Bast, Mohamad Abo Ras, University of Applied Sciences Kiel GmbH, DE
Corinna Grosse-Kockert, Daniel May, Sara Panahandeh, Berliner Nanotest und Desgin, DE
Anu Mathew, Rico Eichhorn, Fraunhofer Institute ENAS, DE
- PP031 Evaluating the Safety Isolation of the Package in an Integrated Power Device**
Thomas Anthony Capobianco, Power Integrations, US

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- PP032 Flexible Control System for Modular One-Phase Interleaved GaN-based Totem Pole PFC Using Real-Time Hardware**
Oleksandr Solomakha, Siddhartha Menon, Manuel Rueß, Swapnil Sunil Roge, Dominik Koch
Ingmar Kallfass, University of Stuttgart, DE
- PP033 A Peak Current Mode Control Method for PFC**
Sean Yu, Texas Instruments, US
- PP034 Adaptive Resonant Controller for a Three-Phase PFC Converter for an On-Board Charge Application**
Rami Troudi, Kelly Ribeiro, Valeo, FR
- PP035 Synthesis of a Field Oriented Control Algorithm by Using two Different Pole-Zero Compensation Approaches**
Marco Denk, Felix Heigel, University of Applied Sciences Coburg, DE
Johannes Schwarzkopf, Roman Filka, Brose Fahrzeugteile, DE
- PP037 Average Current Mode Control and Its Loop Design**
Niklas Schwarz, Texas Instruments, DE
Feng Ji, Texas Instruments, CN
- PP038 Novel Power Feed-Forward Regulation for Dual Stage PFC+DCDC Converters**
Alfredo Medina-Garcia, Pierrick Ausseresse, Martin Krueger, Cristina Martos-Contreras,
Josef Daimer, Infineon Technologies, DE
Manfred Schlenk, Dr. Schlenk Consulting, DE

High Power AC-DC and DC-AC Converter

- PP039 22 kW Bi-directional Wall-box Charger With 1200 V SiC MOSFET**
Sanbao Shi, Cheng Zhang, Yi Zhang, Infineon Semiconductors, CN
Sidorov Vadim, Tomislav Turscak, Infineon Technologies AT

- PP040 Dynamic Switching Frequency Selection for Efficiency Optimization in On-Board Charger PFC Stage Based on Novel SiC MOSFET Power Module**
Giuseppe Aiello, Francesco Gennaro, Dario Patti, STMicroelectronics, IT
Domenico Nardo, STMicroelectronics, DE
- PP041 Design and Optimization of SiC-Based 11kW Motor Drive with High Efficiency**
Iris Liu, Frank Wei, Jianlong Chen, Haiming Zhan, Fulin Zhang, ZongZeng Hu, Wolfspeed, CN
- PP042 Model Design Development for False Turn-on characterization in SiC-Based Active T-Type Converter Considering All Parasitics**
Amir Babaki, Mohammad Sadegh Golsorkhi Esfahani, Thomas Ebel, University of Southern Denmark, DK
Nicklas Christensen, Danfoss Drives, DK
- PP043 Efficiency Investigations of an Auxiliary Resonant Commutated Pole Inverter**
Markus Zocher, Norbert Graß, Nuremberg Institute of Technology, DE
Ralph Kennel, Technical University of Munich, DE
- PP044 A Novel Hybrid Two-Stage AC-DC Converter with Soft-Switched CCM PFC Stage for EVs Charging Applications**
Lei Wang, Sinan Li, University of Sydney, AU
- PP045 A Method for Tuning Leakage Inductance in Transformers**
Rosemary O'Keeffe, Michael Dunleavy, Cathal Sheehan, Bourns Electronics, IE
- PP046 Low Cost High Density 300W/20V AC-DC Converter Enabled by GaN Power ICs**
Tom Ribarich, Xiucheng Huang, Navitas Semiconductor, CN
- PP047 25kVA Grid-Tied Bi-Directional T-Type Inverter with High-Efficiency and High-Power Density Using SiC MOSFETs**
Tamanna Bhatia, Jun Zhang, Sumana Ghosh, Wolfspeed, US
Frank Wei, Wolfspeed, CN
- PP048 Cost-Effective Efficiency Enhancement in AC-DC Converters: A Study Across the Full Load Cycle**
Sebastian Gick, Mark-M. Bakran, University of Bayreuth, DE
Markus Pfeifer, Sebastian Nielebock, Siemens, DE

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- PP049 Next Generation Power Module with Parallel Connected SiC MOSFETs for BEV Traction Inverters**
Kohei Tanikawa, Oji Sato, Kotaro Shibata, Masashi Hayashiguchi, Hiroto Sakai, Yuta Okawauchi, Kenji Hayashi, ROHM, JP
- PP051 Investigation of Common Source Feedback in SiC Power Modules regarding Performance and Short Circuit Robustness**
Dominik Ruoff, Zong Xern Sim, Robert Bosch, DE
Ulrich Burkhard, Reutlingen University, DE
- PP052 HybridPACK Drive Power Modules with SiC-MOSFET's and Monolithic RC- Snubber Chips for Optimized Power Density**
Andre Uhlemann, Thomas Hunger, Andreas Groove, Nikolaj Gorte, Infineon Technologies, DE
- PP053 Robust Auxiliary Power Supply for EVs Based on Innovative STi2GaN 650V IC**
Federica Cammarata, Filippo Scrimizzi, Claudia, Malannino, Andrea Russo, STMicroelectronics, IT
- PP054 Impact of Various Silicon Diodes on the Hybrid Switch Inverter**
Michael Walter, Mark-M. Bakran, University of Bayreuth, DE

- PP055 Advanced Pulse Sequence for Saliency-Based High-Accurate Rotor Position Estimation of Railway Traction Locomotive Motors**
Markus Vogelsberger, ALSTOM, AT
Hans Ertl, Thomas Wolbank, Technical University of Vienna, AT
Eduardo Rodriguez Montero, Wolfram Teppan, LEM, CH

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- PP056 Optimized Half-Bridge Gate-Drive with Low Time-Skew for RC-IGBTs and SiC-MOSFET Dead-Time Control**
Jan Fuhrmann, Hans-Günter Eckel, University of Rostock, DE
Till-Mathis Plötz, Rostocker Kompetenzzentrum für Leistungselektronik, DE
- PP057 Design of a Traction Inverter Based on PCB-Embedded GaN Devices**
Maurizio Tranchero, Luca Bongiovanni, Claudio Romano, Paolo Santero, Ideas & Motion, IT
- PP058 Optimizing Electric Vehicle Performance with GaN Design**
Andrew Patterson, David Green, Ahmed Nejim, Silvaco, UK
- PP059 Fast Analytical Calculation of the Magnetic Field in Permanent Magnet Synchronous Machines with Flux Barriers Including Saturation**
Martin Ackermann, José-Luis Marqués, Claus Hillermeier, Universität der Bundeswehr, DE
- PP060 Modeling and Control of LCL filtered 3L-VSCs in Interleaved Topology**
Adeel Jamal, Gerd Griepentrog, Technical University of Darmstadt, DE
- PP062 Enhancing Safety and Efficiency for Isolated PLC I/O Designs with SPI Daisy Chain**
Travis Lenz, Skyworks Solutions, US
- PP063 Cost-Effective Method to Discharge DC Link Capacitors with SiC Power Modules**
Paul Kanatzar, Brian DeBoi, Stephanie Vinueza, Austin Curbow, Wolfspeed, US

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- PP064 A Study on Circulation Current in Parallel Operation of Transformer less UPS**
Koji Kato, Hisakatsu Igarashi, Akira Sato, GS Yuasa International, JP
- PP065 Design Challenges and Considerations for Gate Drivers of SiC MOSFETS and their Testing**
Niranjan Hegde, Shubha B, Srikrishna N.H, Tektronix, IN
- PP066 A Portable Efficiency Characterization Setup for Technology Demonstration of Power Modules**
Sebastian Tengvall, Ariel Muszkat, Hoà Lê Thanh, Ahmed Ammar, Lotus Microsystems, DK
- PP067 Fast EME Characterization of Bare-Die SiC MOSFETS**
Robert Kragl, Frederik Jülich, Karl Oberdieck, Konstantin Spanos, Robert Bosch, DE
Rik W. De Doncker, RWTH Aachen University, DE
- PP068 Theoretical Comparison of Component-Related Measurement Methods of Photovoltaic Inverters for Long-Term Testing**
Niclas Reitz, Sebastian Sprunck, Ron Brandl, Fraunhofer Institute IEE, DE
Marco Jung, Bonn-Rhein-Sieg University of Applied Sciences, DE
- PP069 Power Cycling Test Optimization Toward Reliability Assessment of Sintered Power Modules**
Robert Graham, Macdermid Alpha Electronic Solutions, US
- PP070 Real-Time Estimation and Sensitivity Analysis of Parasitic Capacitances in Electric Drive Systems**
Mohammadreza Bagheribavaryani, Niklas Langmaack, Technical University of Braunschweig, DE

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- PP071 Parasitic Component Effects of Internal and External Package Level on Switching Performance of SiC Power Module**
Nguyen Nghia Do, Chen-Min Chen, Sheng-Tsai Wu, Yu Tai-Jyun, Jing-Yao Chang, PowerX Semiconductor, TW
- PP072 A Multi-Physics Iterative Approach for Temperature Estimation in SiC Power Module for Electric Vehicle**
Stefano Orlando, Daniela Cavallaro, Marco Papasero, Ludovica Longo, Alessandra Cascio, STMicroelectronics, IT
Domenico Nardo, STMicroelectronics, DE
- PP073 Voltage Balancing Method for Series Connection of 50 SiC MOSFETs**
Antoine Philippe, Guillaume Piquet-Boisson, Van-Sang Nguyen, CEA, FR
Anne-Sophie Descamps, Nicolas Ginot, Christophe Batard, Nantes University, FR
- PP074 A Laboratory-Scale MMC-Based DC System with RCP and PHIL Simulation Capabilities**
Marc René Lotz, Martin Könemund, Ostfalia University, DE
Eugene Tinjinui Ndoh, DLR, DE
Michael Kurrat, Technical University of Braunschweig, DE
- PP075 Film Capacitor Standard Series Digitalization: Electromagnetic & Thermal Modelling implementation in CLARA Web Tool**
Fernando Aunon, TDK Electronics, ES
Fernando Rodriguez, TDK Electronics Components, ES
David Olalla, TDK Electronics Components, DE
- PP076 Accuracy Evaluation and Proposed Dynamic Tuning Procedure of a Compact SiC SPICE Model**
Austin Curbow, Brian DeBoi, Blake Nelson, Wolfspeed, US
- PP077 Investigation of Use-Case-Dependent Modeling Approach for Switched-Mode Power Converter for LVDC Grid Evaluation**
Melanie Lavery, Raffael Schwanninger, Martin Maerz, Friedrich-Alexander-University Erlangen-Nuremberg, DE
- PP078 Averaged Model with Blocking Capability for Solid-State Transformers**
Ahmed Meligy, Rafael Medeiros, Schneider Electric, FR
Ilknur Colak, Schneider Electric, DE
Seddik Bacha, G2Elab, FR

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- PP080 Surfactant-Modified Nanocomposite Thin-Film Capacitors**
Bartosz Gackowski, William Greenbank, Thomas Ebel, University of Southern Denmark, DK
- PP081 Increasing Energy Storage Capabilities of Powder Cores by Adapting the Winding and the Use of Fringing Flux**
Paul Winkler, AnhTuan Luong, Bhartindu Bunny, Wulf Günther, Acal BFi, DE
- PP082 PEEC-Based Thermal Modeling of Passive Components**
Sascha Langfermann, Michael Owzareck, Lukas Fräger, Block Transformatoren-Elektronik, DE
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- PP083 Galvanically Isolated Power Supply for Gate Drivers in High Voltage Applications**
Priyanka Ghosh, Michael Meissner, Klaus F. Hoffmann, Helmut-Schmidt-University, DE

- PP084 Fabrication Technique for Novel Nanocrystalline Cores with High Saturation Polarization and Low Losses**
Merlin Thamm, Inge Lindemann-Geipel, Thomas, Weißgärber, Fraunhofer Institute IFAM, DE
- PP085 Excitation-Dependent Temperature Behavior of the Quasi-Static Hysteresis Loss Energy Density of N87 Ferrite Material**
Jeremias Kaiser, Thomas Dürbaum, Friedrich-Alexander-University Erlangen-Nuremberg, DE
Erika Stenglein, Siemens Energy, DE
- PP087 Passive Methods Limiting Leakage Current in Metal-Oxide Varistor as Voltage Clamping Device used DC Low Voltage Power Electronics-Based Circuit Breakers**
Kenan Askan, Eaton Industries, AT
Radek Kľof, Eaton European Innovation Center, CZ

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- PP088 ESD solutions for 650V Normally-off AlGaIn/GaN HEMTs**
Thanh Hai Phung, Plinio Bau, Sebastian Gaviria-Duque, Dominique Bergogne, Bernard Bancal, Wise-integration, FR
- PP089 A Simulative Study of Measurement Errors During Double Pulse Testing of GaN Devices**
Severin Klever, Rik W. De Doncker, RWTH Aachen University, DE
- PP090 Parallel Connection of GaN FETs: an Experimental Investigation Approach**
Marco Palma, Efficient Power Conversion, IT
Salvatore Musumeci, Vincenzo Barba, Polytechnical University of Turin, IT
- PP091 Repetitive Short Circuits on 650 V GaN**
Adrien Lambert, Laurent Guillot, STMicroelectronics, FR
Hervé Morel, Dominique Planson, Luong-Viet Phung, Pascal Bevilacqua, Ampere Laboratory, FR
- PP092 Comparison of Switching Losses and Dynamic on Resistance of 600 V-Class GaN HEMTs**
André Thönnessen, Joshua Baumgärtner, Carsten Fronczek, Rik W. De Doncker, RWTH Aachen University, DE
- PP093 Performance Evaluation of Deadtime and Gate Resistance for Parallel Connected GaN HEMTs**
Junhyeok Jegal, Minho Kwon, Jong-Pil Lee, Korea Electrotechnology Research Institute, RK
- PP094 Reaching Beyond 1200V: Lateral GaN HEMTs for High-Reliability EV and Industrial Applications**
Kamal Varadarajan, Robert Yang, Alexei, Ankoudinov, Karthick Murugesan, Alexey Kudymov, Sorin Georgescu, John Rongavilla, Doug Kang, Power Integrations, US

SiC Devices and Technologies

- PP095 SmartSiC 150 & 200mm Engineered Substrate: Increasing SiC Power Device Current Density up to 30%**
Eric Guiot, Walter Schwarzenbach, Alexis Drouin, Frédéric Allibert, SOITEC, FR
Tom Becker, Oleg Rusch, Jürgen Leib, Fraunhofer Institute IISB, DE
- PP096 Dynamic Transients in High-Voltage Silicon and 4H-SiC NPN Bipolar Junction Transistors**
Mana Hosseinzadehlsh, Saeed Jahdi, Xibo, Yuan, University of Bristol, UK
Olayiwola Alatise, Jose Ortiz Gonzalez, University of Warwick, UK

- PP097 An Advanced Multi-Aspect Performance Analysis of Planar-gate 1.2 kV SiC Power MOSFETs**
Anja Katerina Brandl, Salvatore Race, Bhagyalakshmi Kakarla, Ivana Kovacevic-Badstübner, Ulrike Grossner, Michael Nagel, ETH Zurich, CH
- PP098 SiC MOSFET Die Sorting and Parallel for Optimal Module Design**
Zhong Ye, Yi Yang, Yangdong Zhou, Qing Wang, Inventchip Technology, CN,
- PP099 Simulation Approach for Radiated Electro-Magnetic Fields Estimation on Acepack Drive SiC Power Module**
Andrea Cusumano, Debora Crimi, Salvatore Oliveri, Alessandra Manzitto, STMicroelectronics, IT

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- PP100 Exact Analysis of Control-to-Output Transfer Functions of PWM-Converters - A Comparison of Two Methods**
Daniel Breidenstein, Sophia Rösel, Thomas Dürbaum, Friedrich-Alexander-University Erlangen-Nuremberg, DE
- PP101 3-Level Flying Capacitor Multilevel Topology with Delta-Sigma Modulation**
Jannik Maier, Philipp Czerwenka, Gernot Schullerus, Eckhard Hennig, Ertugrul Sönmez, Reutlingen University, DE
- PP102 Model Based Controlled Power Converter Test Platform**
Dawid Koczy, Alexander Ernst, Wilfried Holzke, Bernd Orlik, University of Bremen, DE
- PP103 Educational Hardware Trainer for Teaching the Dual Active Bridge in a DC Grid**
Peter van Duijsen, Diego Zuidervliet, Sebastiaan Koning, The Hague University of Applied Sciences, NL
- PP104 Study of the Operating Performance of a FCS-MPC-Controlled Matrix-Converter for PMSM at Different Frequency Ratios**
Robert Zipprich, Bünyamin Tekir, Jan Winter, Marcus Ziegler, University of Kassel, DE
- PP105 Enhancing Reactive Power Capacity in Battery-fed Power Conditioning Systems**
Lucas Araujo, Joseph Banda, Elisabetta Tedeschi, Norwegian University of Science and Technology, NO
- PP106 Pulse Sharing: Achieving High Efficiency and Excellent Regulation in Multi-Output Flyback Power Supplies**
Xingda Yan, Toine Werner, Power Integrations, UK
- PP107 Reliability-Optimized Space Vector Modulation (RO-SVM) for Semiconductors Lifetime Enhancement**
Amin Rezaeizadeh, Silvia Mastellone, University of Applied Sciences and Arts Northwestern Switzerland, CH

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- PP108 Analysis and Optimization of Internal Coupling Interference in Integrated SiC Power Module Based on DBC**
Chenhang Zeng, Cai Chen, Yong Kang, Huazhong University of Science and Technology, CN
- PP109 Multispectral Electroluminescence Sensing of SiC MOSFETs for Junction Temperature and Current Extraction**
Lukas Ruppert, Rik W. De Doncker, RWTH Aachen University, DE
- PP110 SiC-IPM for Compact and Energy Efficient Low-Power Motor Drives**
JongMu Lee, Alpha and Omega Semiconductor, KR
Jun-Ho Lee, Jin-Tae Kim, Alpha and Omega Conductors, KR
Bum-Seok Suh, Alpha and Omega Conductors, RC

- PP111 Concept for a GaN-Based Intelligent Motor Controller with Integrated Failure Prediction for the Inverter and the Drive**
 Christoph Blechinger, Martin Schellenberger, Maximilian Hofmann, Fraunhofer Institute IISB, DE
 Michael Mensing, Marc Gensch, David Westerhoff, Fraunhofer Institute ISIT, DE
 Alexander Stanitzki, Patrick Barylla, Lukas Krupp, André Lüdecke, Fraunhofer Institute IMS, DE
- PP112 Introducing the New 1200 V CIPOS Maxi IM817 Intelligent Power Module for Motor Drive Applications**
 Kihyun Lee, Jinhyeok Kim, Soohyuk Han, Bokkeun Song, Kyoungpil Kang, Minsub Lee, Infineon Technologies, KR
- PP113 Thermal Performance of Infineon's New 600 V CIPOSTM Micro IM241 IPM for Low Power Motor Drive Systems Without Heatsink**
 David Jo, Kim Jingyeok, Song Hyunsoo, Bokkeun Song, Byoungcho Choo, Infineon Technologies, KR
 Laurent Beurenaut, Infineon Technologies, DE

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- PP114 An Adaptive Dead Time Control Based on Switch Node Voltage Derivative**
 Lukas Knappstein, Martin Pfof, TU Dortmund University, DE
- PP115 Coupling Coil Design and Positioning Optimization on New High Power Semiconductor Module for Fast Short Circuit Detection**
 Yannick Dumollard, Emmanuel Batista, Vincent Escrouzailles, Damien Tisne-Grimaud, Alstom, FR
- PP116 Enabling Active Thermal Control via an Adaptive Multi-Voltage Gate Driver**
 Tianlong Albert, Lucas Radon, Rik W. De Doncker, RWTH Aachen University, DE
- PP117 Innovative Gate Drive Method TriC3 for Motor**
 Hisashi Sugie, ROHM, JP
- PP118 A New Class of Solid State Isolators Enhances the Reliability of Solid State Relays**
 Wolfgang Frank, Infineon Technologies, DE
- PP119 A Self-Driving 3-Level Active Gate Driver Network to Control the Switching Slew Rate for SiC MOSFETs**
 Vin Loong Choo, Martin Pfof, TU Dortmund University, DE

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- PP121 Analysis of Long-Term Reliability of SiC in Traction Inverter Considering Vth Instability**
 Chi Zhang, Riccardo Negri, Volvo Cars, SW
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Daniel Urbaneck, Frank Schafmeister, Paderborn University, DE
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Tim McRae, Ramkrishnan Maheshwari, Thomas Ebel University of Southern Denmark, DK
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Sheng-Yang Yu, Texas Instruments, US
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Marius Block, Stefanie Orlik, Wilfried Holzke, Holger Raffel, University of Bremen, DE
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Dimitar Arnaudov, Krasimir Kishkin, Vladimir Dimitrov, Technical University of Sofia, BG
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Steffen Frei, Milad Khani, Gerd Griepentrog, Technical University of Darmstadt, DE
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Oscar Lucia, Hector Sarnago, Ignacio Alvarez, University of Zaragoza, ES

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Sean Yu, Guangzhi Cui, Texas Instruments, CN
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Simone Mazzer, Roberto Rizzolatti, Mario Ursino, Erik Medeossi, Infineon Technologies, AT
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Daniel Haake, Anton Gorodnichev, Matthias Klee, Fabian Schnabel, Fraunhofer Institute IEE, DE
Matthias Bürger, Infineon Technologies, DE
Marco Jung, University of Applied Science Bonn-Rhein-Sieg, DE
- PP234 30kW - 97% Efficiency Isolated DC-DC Converter with Large Input Voltage Range Based on a Boost DAB Association**
Jean-Jacques Huselstein, Francois Forest, University of Montpellier, FR
Olivier Martos, Patrice Levron, Gamma Technologies, FR
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Gean Sousa, Sandip Guha Thakurta, Christos Leontaris, Marcelo Lobo Heldwein, Technical University of Munich, DE

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Damien Lemaitre, Ecrabey Jacques, CEA, FR

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Sachin Shridhar Paradkar, Aalok Bhatt, Francois Perraud, Littelfuse, DE

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- PP246 Maximizing Cost-Efficiency in Electric Drivetrains: A SiC/Si Fusion Switch Approach**
Matthias Ippisch, Tomas Reiter, Michael Niendorf, Waldemar Jakobi, Mark Münzer, Infineon Technologies, DE

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David Zipperstein, Mihail Jefremow, Juergen Schaefer, Arndt Voigtlaender, Infineon Technologies, DE
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- PP252 CO2 Footprint of Medium Voltage DC Solid State Transformer**
Adriana Campos, Astrid Jasi, Konstantin Vershinin, Piotr Dworakowski, SuperGrid Institute, FR

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- PP253 Thermo-Electrical Analysis and Performance: A Comparative Study between Modular and Discrete Approaches**
Stefano Orlando, Daniela Cavallaro, Marco Papasero, Ludovica Longo, Alessandra Cascio, STMicroelectronics, IT
Domenico Nardo, STMicroelectronics, DE
- PP254 Impact of Parameter Spread in Parallel-Operated SiC MOSFETs for Hard-Switching Conversion**
Andrea Piccioni, Niklas Seltner, Infineon Technologies, AT
- PP255 Assessment of the Rds,on of SiC MOSFET Dies Through Kelvin Wire Connection**
Philipp Rehlaender, Klaus Neumaier, Kaone Bogopa, Lukas Richert, Sara Kuzmanoska, onsemi, DE
- PP256 Challenges in Scaling SiC Single-Chip Measurements to Corresponding Power Modules**
Hao Wang, Felix Kayser, Florian Sawallich, Pham Ha Trieu To, Hans-Günter Eckel, University of Rostock, DE
- PP257 Switching Performance Evaluation of High-Power 1.7 kV SiC MOSFET Modules using a Common Busbar Design**
Sebastian Neira, Mason Parker, Stephen J. Finney, Paul D. Judge, University of Edinburgh, UK
- PP258 Characterizing the Switching Behavior of a 1.2 kV mixed SiC JFET and MOSFET Half Bridge**
Tim Ringelmann, Mark-M. Bakran, University of Bayreuth, DE

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- PP259 Performance Evaluation of the Packaging of SiC Diodes in a 6.78 MHz Wireless Power Transfer System**
Ioannis Nikiforidis, Paul Mitcheson, Prateek Wagle, Imperial College London, UK
Shu Takeuchi, Masashi Fukai, Kengo Tashiro, Sansha electric MFG, FI
- PP260 Voltage Waveform Generation for Sawyer-Tower Coss Loss Measurements Using a Hybrid Power Converter**
Malachi Hornbuckle, Steven Abrego, Katherine Liang, Sara Davidova, Zikang Tong, Juan Rivas, Stanford University, US
- PP261 Evaluation of SiC Devices for Over 500kHz Application Based on Buck Circuit**
Minli Jia, Sicheng Gong, Kang Liu, Zhen Zhou, Navitas Semiconductor, CN
Hao Sun, Navitas, CN
- PP262 Linearization of Drain-Source Capacitances for Antiserial Configured SiC MOSFETs in High Frequency Solid State Switches**
Lars Dresel, Gerd Griepentrog, Vefa Karakasli, Technical University of Darmstadt, DE

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- PP263 Effects of Non-killer Defects on SiC MOSFET Short-circuit Ruggedness and Reliability**
Sara Kuzmanoska, Prajeesh Karimbankara, Kaone Bogopa, Philipp Rehlaender, Swapna Sunkari, Hrishikesh Das, onsemi, DE
- PP264 Dynamic Reverse Bias Test: Electro-Thermal Characterization of SiC MOSFETs**
Giuseppe Mauromicale, Alessandro Sitta, Michele Calabretta, Luciano Salvo, STMicroelectronics, IT
- PP266 Radiation Hardness of SiC Based Inverters Based on an EV Mission Profile**
Hadiuzzaman Syed, Stephan Schwaiger, Sudhanshu Goel, Alberto Martinez-Limia, Klaus Heyers, Robert Bosch, DE
- PP267 Rapid Short Circuit Protection Using didt Detection for SiC Power Modules**
Koki Samura, Kentaro Yoshida, Kakeru Iwashita, Seiichiro Inokuchi, Mitsubishi Electric, JP
- PP268 Comparison of Dynamic Gate Stress Test Results of SiC MOSFETs**
Mathias Gebhardt, Gabriel Lieser, SET, DE
- PP279 Extending SiC MOSFET Short-Circuit Withstanding Time by Two-Level Turn-Off Gate Driving**
Kwokwai Ma, Dinesh Palaniappan, Infineon Technologies, SG
- PP270 Experimental Investigations on Parasitic Turn-on of 1.2kV SiC MOSFET Discrete Devices**
Thanh-Toan Pham, Jimmy Franchi, Martin Domeij, onsemi, SW
Kwangwon Lee, onsemi, KR
Sara Kuzmanoska, onsemi, DE
- PP271 Behavior Modelling the Short Circuit Characteristics of SiC MOSFETs Using Compact Models**
Qing Sun, Andreas Huerner, Rudolf Elpelt, Infineon Technologies, DE

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- PP273 Thermal Analysis and Modelling of Charging Stations for Electric Vehicles**
Ruben Kopischke, Christian Koppe, Tim Schmidt, Mohamed Ayeb, Ludwig Brabetz, University of Kassel, DE

- PP274 Junction Temperature Measurement of a 3.3 kV Silicon Carbide MOSFET Power Module**
 Michael Gleissner, Mark-M. Bakran, University of Bayreuth, DE
 Matthias Bürger, Infineon Technologies, DE
- PP275 Innovative 3D Power Module Defaults Detection via Thermal Impedance Analysis and Simulations**
 Louis Alauzet, Anne Castelan, Sophie Regnier, Jean-Pierre Fradin, Alexandre Dezalay, ICAM, FR
 Patrick Tounsi, University of Toulouse, FR
- PP276 Thermal Characterization of an Air-Cooled PEBB Based on SiC MOSFET Power Modules**
 Alexandre Marie, Jean-Pierre Fradin, Benjamin Vieillefosse, Icam School of Engineering, FR
 Maria Alejandra Castellanos Taita, Joseph Fabre, SCLE-SFE, FR
 Philippe Ladoux, LAPLACE, FR
- PP277 Thermal Behaviour of SiC MOSFET with Planar Packaging Technology**
 Yijun Ye, Alexander Hensler, Thomas Bigl, Siemens, DE
 Thomas Basler, Josef Lutz, Chemnitz University of Technology, DE

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- PP279 Implementing Module Health Monitoring in EV Traction Inverters**
 Karol Rendek, Adam Matajs, ON Semiconductor, SK
- PP280 Reliability Tests of Copper Thick-Film Substrates for Power Electronic Applications**
 Henry Barth, Lars Rebenklau, Fraunhofer Institute IKTS, DE
 Sebastian Letz, Fraunhofer Institute IISB, DE
- PP281 Power Module Solutions with Improved Reliability for Elevator Drive Applications**
 Tiago Jappe, Matthias Tauer, Ábel Tőkés, Vincotech, DE
- PP282 Fail-Operational LLC Topologies with Fault-Tolerance Integrated Redundant Capabilities**
 Aswathy M. Prince, Ayman Ayad, Vitesco Technologies, DE
- PP283 Thermal and Reliability Optimization of Clips in SiC MOSFET Power Modules**
 Zexiang Zheng, Jianwei Lv, Yiyang Yan, Jiaxin Liu, Cai Chen, Yong Kang, Huazhong University of Science and Technology, CN
- PP284 Condition Monitoring of a GaN Full-Bridge by Means of Forward Voltage in Continuous Operation**
 Michael Vogt, Nando Kaminski, Alexander Brunko, University of Bremen, DE
 Gerrit Braun, Klaus Rigbers, SMA Solar Technology, DE
- PP285 A Simple and Low Cost Overcurrent Protection System Based on Commercial Shunt for Wide-Bandgap Devices**
 Emanuele Martano, Giovanni Busatto, Annunziata Sanseverino, University of Cassino and Southern Lazio, IT
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- PP286 SVM-Based Fault-Tolerant Control for a Cascaded H-Bridge Multilevel Converter under Multiple Open-Circuit Switch Faults**
 Dong Xie, Thomas Basler, Chemnitz University of Technology, DE
 Hongjian Lin, City University of Hong Kong, HK; Chunxu Lin, Southwest Jiaotong University, CN

- PP287 Revolutionizing Mobility: The Second Life of Onboard Charging Systems in Commercial Vehicles**
Ajay Krishna Voppu Muralikrishna, Bjorn Isaksson, SiNIX Group, SW
Viswanathan Ganesh, Pennsylvania State University, US; Yujing Liu, Chalmers University of Technology, SW

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- PP288 A Behavioral Transient Model for IGBT Device with Anti Parallel Freewheeling Diode**
Shiwu Zhu, Chunlin Zhu, Wei Gong, Nexperia, UK
Qi Huang, Ken Zhang, Huiling Zuo, Junli Xiang, Nexperia, CN
Katsuaki Saito, Nexperia, JP
- PP289 Parameter Extraction for an ANN-assisted IGBT Model in Transient Simulations**
Huaiyuan Zhang, Steven Lee, Keysight Technologies, US
Abby Shih, Keysight Technologies, DE
Stefan Haensel, Zeeshan Umar, Felix Zeys, Siemens, DE
- PP290 Fabrication of 600V RC-IGBT Using 300mm Wafer**
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- PP291 Next Level of Power Module Solution for PV C&I String Inverter with 1200V H7 Technology in Easy3B Package**
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- PP292 Analysis of MOSFET Switching Losses in Resonant Converters Using Electrical and Thermal Measurements and Loss Trends with MOSFET Size Variation**
Alfio Scuto, Marco Ventimiglia, Giuseppe Sorrentino, Gaetano Belverde, STMicroelectronics, IT
- PP293 OptiMOS 6 135V for High Power Motor Drives**
Kunal Jha, Kapil Kelkar, Infineon Technologies, US
Tien Quang Tran, Josef Mohammed, Infineon Technologies, AT
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- PP294 Auto Power-SOI: Shaping the Future of Battery Monitoring Technology**
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Shu Ee Ong, Skyworks Solutions, US
- PP296 Paris Law Applied to Wire Bonds Degradation Using Crack Growth Measurement**
Merouane Ouhab, Pierre-Yves Pichon, Mitsubishi Electric, FR
- PP297 Condition Monitoring Technique of Power Electronic Modules via Square-Wave Gate Signal Excitation**
Isabel Austrup, Rik W. De Doncker, RWTH Aachen University, DE
- PP298 Statistics-based Lifetime Simulation Environment for Power Modules incorporating Degradation Models**
Karthik Debbadi, Martin Votava, Yoann Pascal, Marco Liserre, Fraunhofer Institute ISIT, DE
Gopal Mondal, Sebastian Nielebock, Siemens, DE
- PP299 Power Cycling Results for Reliability Studies of SiC-Inverters**
Robert Keilmann, Florian Lippold, Regine Mallwitz, Technical University of Darmstadt, DE
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- PP301 Prognostic Analysis of IGBT Health: Real-Time On-State Voltage Prediction through Machine Learning**
Tanya Thekemuriyil, Jaspera Dominique Rohner, Renato Amaral Minamisawa, University of Applied Sciences and Arts Northwestern Switzerland, CN
- PP302 Robustness Analysis of Temperature-Sensitive Electrical Parameters of IGBTs**
Laurids Schmitz, Rik De Doncker, RWTH Aachen University, DE
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- PP303 Observation of Thermal-Resistance Increase of Degraded IGBT Modules by VCE (sat) Measurement in a Chopper Circuit**
Kazunori Hasegawa, Hisaki Ueda, Kanta Hara, Satoshi Nakano, Wataru Saito, Kyushu Institute of Technology, JP
Nobuyuki Shishido, Kindai University, JP
Tamotsu Ninomiya, NPERC-J, JP

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Steffen Frei, Gerd Griepentrog, Technical University of Darmstadt, DE
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Tobias Haas, Theo Zeißel, Technical University of Applied Sciences Würzburg-Schweinfurt, DE
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Felix Eichler, Markus Meißner, Matthias Meißner, Steffen Bernet, Dresden University of Technology, DE
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Sanbao Shi, Cheng Zhang, Infineon Semiconductors, CN
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Tim McRae, Thomas Ebel, Kasper Paasch, University of Southern Denmark, DK
- PP310 Implementation and Control of Optimized Pulse Patterns for Salient Permanent Magnet Synchronous Machines in Electric Vehicles**
Maximilian Hepp, Michael Saur, Wolfgang Wondrak, Mercedes-Benz, DE
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- PP312 Fault-Tolerant Operation Analysis of a Five-Phase Three-Level TNPC Inverter for Electric Aircraft Propulsion Systems**
Chanuch Chaisakdanugull, Klaus F. Hoffmann, Helmut-Schmidt-University, DE

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- PP315 Analysis of Analogue Current and Flux Balancing for the Dual-Active-Bridge Converter**
Christophe Basso, Future Electronics, FR
- PP316 Design and Optimization of a Single-Stage Photovoltaic Microinverter with Integrated Magnetics**
Jin Wen, Jiajia Guan, Chenhang Zeng, Yijie Huang, Zongheng Wu, Wenzhe Xu, Cai Chen, Yong Kang, Huazhong University of Science and Technology, CN
- PP317 Experimental Investigation of Class Φ Inverter Under Various Load Conditions**
Baptiste Daire, Christian Martin, Fabien Sixdenier, Charles Joubert, Loris Pace, Ampere Laboratory, FR
- PP318 Analysis, Modeling, Design, and Limitations of Current Injection based UPF Rectifier with Small DC-Link Capacitor**
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Martin Knecht, Jens Czichon, Marc Buschkuehle, Infineon Technologies, DE
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- PP323 Generalized Switching Sequence for Voltage Balancing in a Flying Capacitor DC-DC Converter with Quasi-2-Level Modulation**
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- PP324 Optimization-Based Sizing of a Modular Multilevel Converter Based on 650 V GaN Modules for New LVDC/MVDC Grids**
Gregoire Le Goff, Corinne Alonso, University of Toulouse, FR
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Liska Steenbock, Jan Boris Loesenbeck, University of Applied Sciences and Arts Bielefeld, DE
- PP326 Single-Stage LED Driver Based on Coupled Inductor Power Factor Correction and LLC Converter**
Alireza Ramezan Ghanbari, Sayed Reza Afzali Arani, Heinz Seyringer, V-research, AT
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Yusi Liu, Andrew Yang, onsemi, US
- PP328 Environmental Impact of Modular Power Electronics Systems Considering Diagnostic-Driven Unit Replacement**
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- PP329 Switching Performance Comparison of 3.3 kV SiC MOSFET and Si IGBT Power Modules for Railway Traction Systems**
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- PP330 Comparison of Three-Level Inverter Topologies for MVDC Reversible Railway Substations**
Luc Bimmel, Erick Brito, University of Toulouse, FR
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- PP331 Control of Bidirectional Power Flow in Railway Catenary Overhead Lines**
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- PP332 A Rail Traction Converter Platform Based on Power Module Implementations with 450 A, 600 A and 800 A 3.3 kV IGBT Modules**
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- PP333 Comparison of Selected Megawatt-Level Traction Converter Power Module Implementations in Terms of Commutation Inductance and Practicality**
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- PP335 Modeling and Simulation of Fluxgate Based Current Sensor**
Yunus Çay, The Center for Solar Energy Research and Applications, TR
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- PP336 Sigma-Delta Based Current Acquisition with Reduced Settling Time**
Joschka Randerath, Jens Onno Krahn, Cologne University of Applied Sciences, DE
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Lennart Hoffmann, Jens Friebe, University of Kassel, DE

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Lukas Radomsky, Matthias Klintz, Regine Mallwitz, Technical University of Darmstadt, DE
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Matthias Neuner, Maurizio Incurvati, Davide Bagnara, MCI Internationale Bildung & Wissenschaft, AT
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- PP342 Highly-Integrated, Flexible Power Solution for Aerospace 5kVA – 20 kVA Motor Drive Applications**
Alain Calmels, Microchip Technology, FR
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Jeff Kugener, Ankit Pal, Stefan Kazula, DLR, DE
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Christian Mühlfeld, Jens Onno Krah, Cologne University of Applied Sciences, DE
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Fabian Groom, Hamzeh Beiranvand, Görkem Can, Marco Liserre, Kiel University, DE
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Florian Fenske, Paul Ott, mdexx Magnetronic Devices, DE
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Jiajia Guan, Jin Wen, shaungxi zhu, Zongheng Wu, Cai Chen, Yong Kang, Huazhong
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- PP356 Testing the Primary-Secondary Coil Coupling of High-Frequency Transformer Implemented on ETD and Toroidal Cores**
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